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Microwave induced negative resistance states in 2D electron gas with periodic modulation

Manuel Torres*
Instituto de Física, Universidad Nacional Autónoma de México, Apdo. Postal 20-364, México D.F. 01000, México

Alejandro Kunold
Departamento de Ciencias Básicas Universidad Autónoma Metropolitana Azcapotzalco,
Av. San Pablo 180, Col. Reynosa Tamaulipas, Azcapotzalco, México D.F. 02200, México

We study the microwave-induced photoconductivity of a two-dimensional electron system (2DES) in the presence of a magnetic field and a two-dimensional modulation. The microwave and Landau contributions are exactly taken into account, while the periodic potential is treated perturbatively. The longitudinal resistivity exhibits oscillations, periodic in ω/ω_c. Negative resistance states (NRS) develop for sufficiently high electron mobility and microwave power. This phenomenon appears in a narrow window region of values of the lattice parameter (a), around $a \sim l_B$, where l_B is the magnetic length. It is proposed that these phenomena may be observed in artificially fabricated arrays of periodic scatterers at the interface of ultraclean heterostructures.

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Novel strong magnetoresistance oscillations with the appearence of zero resistance states (ZRS) were recently discovered[1,2], when ultraclean $GaAs/Al_xGa_{1-x}As$ samples were subjected to microwave irradiation and moderate magnetic fields. It is believed that the ZRS are probably originated from the evolution of negative resistance states (NRS)[3]. Nowadays two distinct mechanisms that produce negative longitudinal resistance are known: (i) the impurity scattering mechanism[4,5] and (ii) the inversion population mechanism[6]. Although the experiments described above do not include the effect of periodical potential modulations, exploring its physical consequences is worthwhile, see the references[7],[8] and[9]. In this work we make a theoretical study of the microwave photoconductivity of a 2DES in the presence of a magnetic field and a two-dimensional modulation.

Consider the motion of an electron in two dimensions subject to a uniform magnetic field $\mathbf{B}$ perpendicular to the plane, a periodic potential V and driven by microwave radiation. The dynamics is governed by the Schrödinger equation

$$i\hbar\frac{\partial\Psi}{\partial t} = H\Psi = \left[H_{\{B,\omega\}} + V(\boldsymbol{r})\right]\Psi\,, \qquad\qquad H_{\{B,\omega\}} = \frac{1}{2m^*}\mathbf{\Pi}^2\,, \tag{1}$$

here $H_{\{B,\omega\}}$ is the Landau hamiltonian coupled to the radiation via the covariant derivative: $\mathbf{\Pi} = \mathbf{p} + e\mathbf{A}$, with $\mathbf{A} = -\frac{1}{2}\boldsymbol{r}\times\boldsymbol{B} + Re\left[\frac{\boldsymbol{E}_\omega}{\omega}\exp\{-i\omega t\}\right]$. The superlattice potential is decomposed in a Fourier expansion: $V(\mathbf{r}) = \sum_{m\,n} V_{m\,n}\exp\left\{i2\pi\left(\frac{m\,x}{a}+\frac{n\,y}{b}\right)\right\}$. We shall assume: (i) a weak modulation $|V| \ll \hbar\omega_c$ and (ii) the clean limit $\omega\,\tau_{tr} \sim \omega_c\,\tau_{tr} >> 1$; here τ_{tr} is the transport relaxation time that is estimated using its relation to the electron mobility $\mu = e\tau_{tr}/m^*$. Based on these conditions it is justified to consider the exact solution of the microwave driven Landau problem and treat the periodic potential effects perturbatively.

A three step procedure is enforced in order to solve the problem posed by Eq. (1): (i) $H_{\{B,\omega\}}$ can be exactly diagonalized by a transformation of the form $W^\dagger H_{\{B,\omega\}} W = \omega_c\left(\frac{1}{2} + a_1^\dagger\,a_1\right) \equiv H_0$, with the $W(t)$ operator given by[5]

$$W(t) = \exp\{i\eta_1\Pi_y\}\exp\{i\zeta_1\Pi_x\}\exp\{i\eta_2\mathcal{O}_x\}\exp\{i\zeta_2\mathcal{O}_y\}\}\exp\{i\int^t\mathcal{L}dt'\}, \tag{2}$$

where the functions $\eta_i(t)$ and $\zeta_i(t)$ represent the solutions to the classical equations of motion associated with the Lagrangian $\mathcal{L} = \frac{\omega_c}{2}\left(\eta_1^2+\zeta_1^2\right) + \dot{\zeta}_1\eta_1 + \dot{\zeta}_2\eta_2 + el_B\left[E_x\left(\zeta_1+\eta_2\right) + E_y\left(\eta_1+\zeta_2\right)\right]$. The center-guide operators are defined according to: $\sqrt{eB}\,\mathcal{O}_x = \Pi_x + eBy\,, \quad \sqrt{eB}\,\mathcal{O}_y = \Pi_y - eBx$. These operators generate the magnetic-translation algebra: $[\Pi_i,\Pi_j] = iB\,\delta_{ij}, \quad [\mathcal{O}_i,\mathcal{O}_j] = -iB\,\delta_{ij} \quad [\Pi_i,\mathcal{O}_j] = 0$. (ii) Applying the W-transformation, the Schrödinger Eq. (1) becomes $i\hbar\frac{\partial\Psi^{(W)}}{\partial t} = \left(H_0 + V_W(t)\right)\Psi^{(W)}$, where $V_W(t) = W(t)V(\boldsymbol{r})W^{-1}(t)$ and $\Psi^{(W)} = W(t)\Psi$. Notice that the periodic potential acquires a time dependence brought by the $W(t)$ transformation. (iii) The problem is now solved in terms of an evolution operator $U(t)$, using the interaction representation and first order time dependence perturbation theory: $U(t) = 1 - i\int_{-\infty}^{t} dt'\left[W^\dagger(t')V(\mathbf{r})W(t')\right]_I$. The solution to the original Schrödinger equation has been achieved by means of three successive transformations $|\Psi_\mu(t)\rangle = W^\dagger\,\exp\{-iH_0 t\}\,U(t-t_0)\,|\mu\rangle$. The explicit expressions for the matrix element of these operators in the Landau-Floquet base appear in detail in references[5,9].

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* Corresponding author: e-mail: torres@fisica.unam.mx.

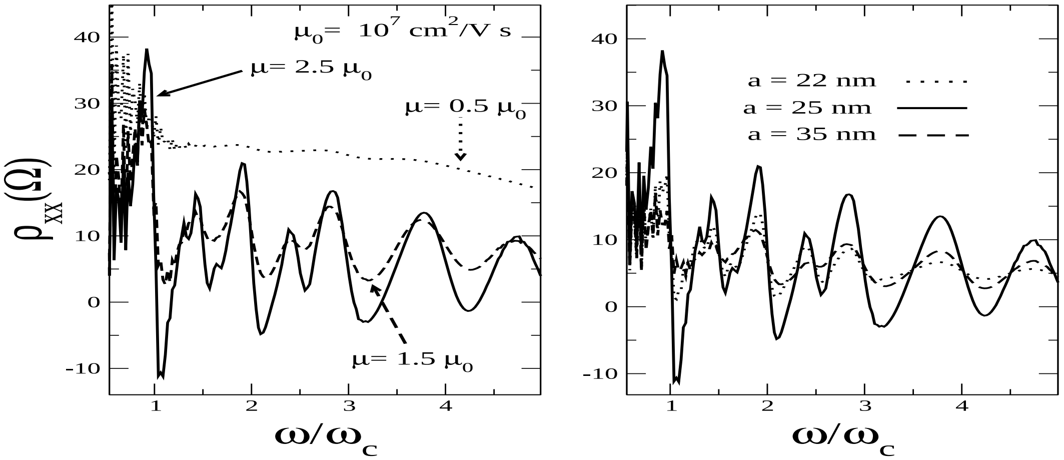

FIG. 1: (a) Longitudinal resistivity as a function ω/ω_c for three values of the electron mobility: $\mu = 0.5 \times 10^7\, cm^2/Vs$ dotted line, $\mu = 1.5 \times 10^7\, cm^2/Vs$ dashed line, and $\mu = 2.5 \times 10^7\, cm^2/Vs$ continuos line. In this case $a = 25\, nm$. (b) ρ_{xx} versus ω/ω_c for three values of the lattice parameter: $a = 22\, nm$ dotted line, $a = 25\, nm$ continuos line, and $a = 35\, nm$ dashed line; in this case $\mu = 2.5 \times 10^7 cm^2/Vs$. The microwave polarization is linear transverse (with respect to the current), with $f = 100\, Ghz$ and $|E_\omega| = 15\, V/cm$. The other parameters are selected as follows: $V_0 = 0.05\, meV$, $m^* = 0.067\, m_e$, $\epsilon_F = 10\, meV$, $T = 1\, K$.

The usual Kubo formula for the conductivity must be modified in order to include the Floquet dynamics[5]. The longitudinal and Hall conductivities are separated in a dark and microwave induced contributions[9]. Here we quote the result for the microwave induced longitudinal photoconductivity

$$\sigma_{xx}^{(MM)} = \frac{e^2 l_B^2}{\pi\hbar} \int d\mathcal{E} \sum_{\mu\nu} \sum_{l} \sum_{m\,n} Im G_\mu \left(\mathcal{E}\right) B^{(l)}\left(\mathcal{E}, \mathcal{E}_\nu\right) \left| q_n^{(y)}\, J_l\left(|\Delta_{m\,n}|\right) V_{m\,n} D_{\mu\nu}(\tilde{q}_{mn}) \right|^2, \tag{3}$$

where $l_B = \sqrt{\frac{\hbar}{eB}}$ is the magnetic length, $q_m^{(x)} = 2\pi m/a$, $q_n^{(y)} = 2\pi n/b$, and $B^{(l)}$ is given by

$$B^{(l)}(\mathcal{E}, \mathcal{E}_\nu) = -\frac{d}{d\mathcal{E}_0} \left\{ \left[f(\mathcal{E} + l\omega + \mathcal{E}_0) - f(\mathcal{E})\right] Im\, G_\nu(\mathcal{E} + l\omega + \mathcal{E}_0) \right\} \Big|_{\mathcal{E}_0 = 0} . \tag{4}$$

Broadening effects are included phenomenologically choosing a Gaussian representation for the density of states

$$Im\, G_\mu(\mathcal{E}) = \sqrt{\frac{\pi}{2\Gamma_\mu^2}} \exp\left[-(\mathcal{E} - \mathcal{E}_\mu)^2/(2\Gamma_\mu^2)\right], \qquad \Gamma_\mu^2 = \frac{2\beta\hbar^2\omega_c}{(\pi\tau_{tr})} . \tag{5}$$

In Eq. (3), $J_l\left(|\Delta|\right)$ is the Bessel function with $\Delta = \frac{\omega_c l_B^2 eE}{\omega(\omega^2 - \omega_c^2 + i\omega\Gamma)} \left[\omega\left(q_x e_x + q_y e_y\right) + i\omega_c\left(q_x e_y - q_y e_x\right)\right]$, where $\boldsymbol{e}$ is the microwave polarization vector. $D^{\nu\mu}\left(\tilde{q}\right) = e^{-\frac{1}{2}|\tilde{q}|^2} \tilde{q}^{\nu-\mu} \sqrt{\frac{\mu!}{\nu!}} L_\mu^{\nu-\mu}\left(|\tilde{q}|^2\right)$, with L_μ^μ being the generalized Laguerre polynomial and $\tilde{q} = i l_B(q_x - i q_y)/\sqrt{2}$. The parameter $\beta \approx 10.5$ takes into account the difference of the transport scattering time τ_{tr} from the single-particle lifetime τ_s.

In our calculations it is assumed that a superlattice is cleaved at the interface of an ultraclean $GaAs/Al_xGa_{1-x}As$ heterostructure with high electron mobility. We shall consider a square lattice potential of the form $V(\mathbf{r}) = V_0\left[\cos\left(\frac{2\pi x}{a}\right) + \cos\left(\frac{2\pi y}{a}\right)\right]$. Negative magnetoresistance requires ultra-clean samples, the phenomenon appears when the electron mobility exceeds a threshold μ_{th}. Figure (1a) displays ρ_{xx} $v.s.$ ω/ω_c plots for three selected values of μ. For $\mu \approx 0.5 \times 10^7 cm^2/Vs$ an almost linear behavior ρ_{xx} is clearly depicted (except in the Shubnikov-deHass region). As the electron mobility increases to $\mu \approx 1.5 \times 10^7 cm^2/Vs$, resistance oscillations periodic in ω/ω_c are clearly observed. However, several NRS appear only when the mobility is increased to $\mu \approx 2.5 \times 10^7 cm^2/Vs$. The explanation for the NRS can be traced down to Eqs. (3) and (4); the longitudinal photoconductivity contains a new contribution proportional to the derivative of the density of states: $\frac{d}{d\mathcal{E}} Im\, G_\nu(\mathcal{E} + l\omega)$. Due to the oscillatory structure of the density of states this extra contribution takes both positive and negative values. This term is proportional to the electron mobility, hence for sufficiently high mobility the new contribution dominates over the dark contribution, leading to negative conductivity states. Figure (1b) shows that NRS appear only in a narrow window of values of a around a^*, for which the oscillations amplitude of ρ_{xx} attains its maximum. It is found that: $a^* \sim \pi l_B/\sqrt{2}$. Unlike the semiclassical origin of magnetoresistance oscillations observed in an antidot array for commensurate values of the ratio R_c/a, these conductance oscillations have a quantum origin and would only appear in a narrow window of values around $a \sim l_B$.

In conclusion, it is proposed that the combined effects of: periodic modulation, perpendicular magnetic field, plus microwave irradiation of 2DES predicts the existence of interesting oscillatory conductance phenomena, with the possible development of NRS.

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